

# OKI electronic components

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## OCM1□4, 1□5 SERIES

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Low Output-capacitance Type Optical MOS Relay For DC Load Only

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### GENERAL DESCRIPTION

The OCM1□4 and OCM1□5 Series are optical MOS relays for DC load only that provide high-speed response and are capable of handling high-frequency signals. The input portion is an infrared light emitting diode. The output portion uses a combination of low-capacitance VD-MOS (Vertical Diffusion MOS) FETs and photodiode arrays. The device is encased in an extremely small 6-pin plastic DIP or SMD-type (gull-wing) package.

The optical MOS relay switch may be used in applications that currently use mechanical relay switches, but offers smaller size, noise-free switching, and electronic circuit compatibility because of its non-mechanical operation. Optical MOS relay switches also dissipate less power than equivalent bipolar devices at lower switching frequencies.

### FEATURES

- Infinitesimally small control voltage
- Excellent high-frequency characteristics (>30 dB isolation at 10 MHz)
- High-speed response ( $t_{ON}$  and  $t_{OFF}$  is 200  $\mu$ s or less)
- Low leak current
- No chattering or switch bounces
- No mechanical switching noises
- Small size and easy mounting (6-Pin plastic DIP or SMD-type [gull-wing] package)

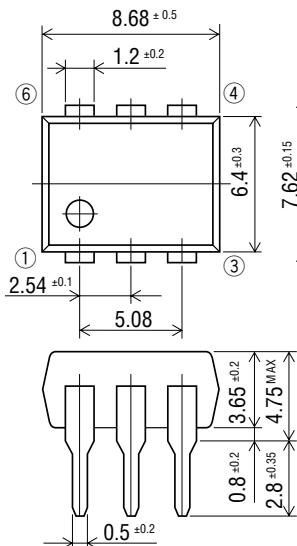
### APPLICATIONS

- Measurement equipment
- Audio-visual equipment
- Home electronics
- Automatic meter reading equipment
- Other applications requiring small size or high performance
- Other applications requiring non-contact switches

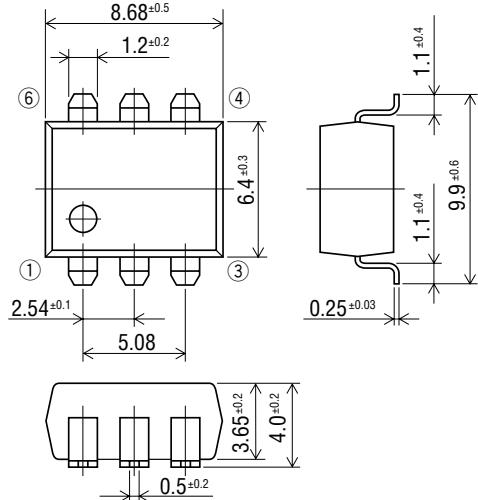
## PIN CONFIGURATION

(Unit: mm)

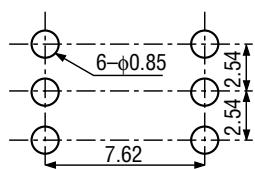
## • DIP Type



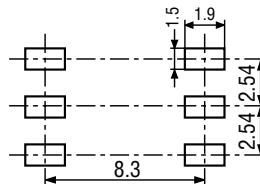
## • SMD Type (gull-wing)



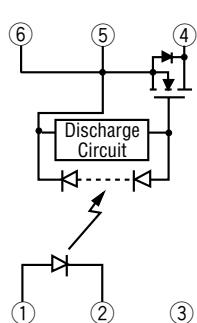
## • Through hole (Bottom view)



## • Mounting pad (Top view)



## • Pin Connection Diagram



- |            |           |
|------------|-----------|
| 1: Anode   | (LED)     |
| 2: Cathode | (LED)     |
| 3: NC      |           |
| 4: Drain   | (MOS FET) |
| 5: Source  | (MOS FET) |
| 6: Source  | (MOS FET) |

## ABSOLUTE MAXIMUM RATINGS

(Ambient temperature Ta=25°C)

Product Name				OCM104 OCM105	OCM114 OCM115	OCM124 OCM125	OCM144 OCM145
Parameter	Symbol	Condition	Unit				
Input Characteristics	Continuous Forward Current	I <sub>F</sub>		mA	50		
	Derating Factor of Continuous Forward Current	ΔI <sub>F</sub>		mA/°C	Refer to [Derating Factor of Continuous Forward Current] of characteristics data		
	Peak Forward Current	I <sub>FM</sub>	Pulse 10 ms Cycle 10 ms	A	0.5		
	Reverse Voltage	V <sub>R</sub>		V	5		
Output Characteristics	Power Dissipation	P <sub>DL</sub>		mW	75		
	Load Voltage	V <sub>OFF</sub>		V	60	100	200
	Load Current	I <sub>ON</sub>		mA	100	70	50
	Derating Factor of Load Current	ΔI <sub>ON</sub>		mA/°C	Refer to [Derating Factor of Load Current] of characteristics data		
	Surge Load Current	I <sub>SUG</sub>	Pulse width 1 ms 1shot	A	0.1	0.07	0.025
	Power Dissipation	P <sub>D</sub>		mW	300		
	Total Power Dissipation	P <sub>tot</sub>		mW	325		
	Isolation Voltage	V <sub>IO</sub>		V(rms)	1500 OCM104 OCM114 OCM124 OCM144 4000 OCM105 OCM115 OCM125 OCM145		
Operating Temperature		T <sub>opr</sub>		°C	−40 to +85		
Storage Temperature		T <sub>stg</sub>		°C	−40 to +100		

## ELECTRICAL CHARACTERISTICS

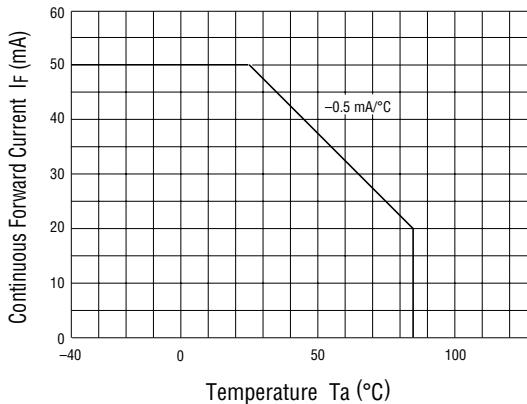
(Ambient temperature Ta=25°C)

Product Name				OCM104 OCM105	OCM114 OCM115	OCM124 OCM125	OCM144 OCM145		
Parameter	Symbol	Condition	Unit						
Input Characteristics	Forward Voltage	V <sub>F</sub>	I <sub>F</sub> =10 mA	Min. Max.	V	1.0			
						1.3			
	Reverse Current	I <sub>R</sub>	V <sub>R</sub> =5 V	Max.	μA	10			
	Input Current *1	I <sub>FA</sub>	I <sub>ON</sub> =Rating	Max.	mA	5			
Output Characteristics	Input Current	I <sub>FR</sub>	V <sub>OFF</sub> =Rating I <sub>ON</sub> =100 μA	Min.	mA	0.2			
	On-resistance Recovery	R <sub>ON</sub>	I <sub>F</sub> =10 mA	Min.	Ω	10	20	50	150
			I <sub>ON</sub> =100 mA	Typ.		15	32.5	75	300
			Time to flow current is within one second	Max.		20	45	100	450
Coupling Characteristics	Off-state Leakage Current *2	I <sub>OFF</sub>	V <sub>OFF</sub> =Rating	Max.	nA	1.0			
	Output Terminal Capacitance	C <sub>OUT</sub>	V <sub>OFF</sub> =50 V f=1 MHz	Typ.	pF	7			
	Input-to-output Capacitance	C <sub>IO</sub>	f=1 MHz	Typ.	pF	1.3			
	Turn-on Time	t <sub>ON</sub>	I <sub>F</sub> =10 mA I <sub>ON</sub> = OCM104, 105:10mA OCM114, 115:10mA OCM124, 125: 4mA OCM144, 145: 1mA	Typ. Max.	μs	30			
	Turn-off Time	t <sub>OFF</sub>		Typ. Max.	μs	200			
						60			
						200			

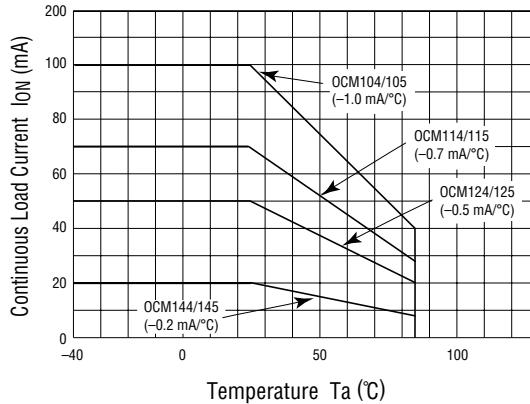
\*1 Can correspond to special specification I<sub>FA</sub><3.0 mA\*2 Can correspond to special specification I<sub>OFF</sub><0.1 nA

## TYPICAL CHARACTERISTICS

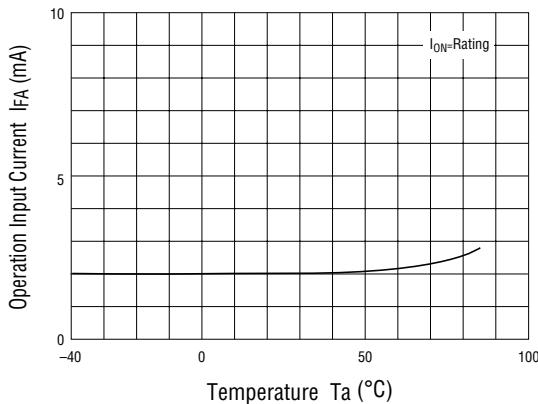
- Derating Factor of Continuous Foward Current



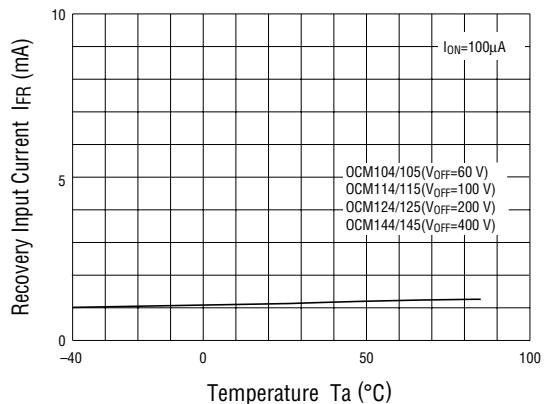
- Derating Factor of Load Current



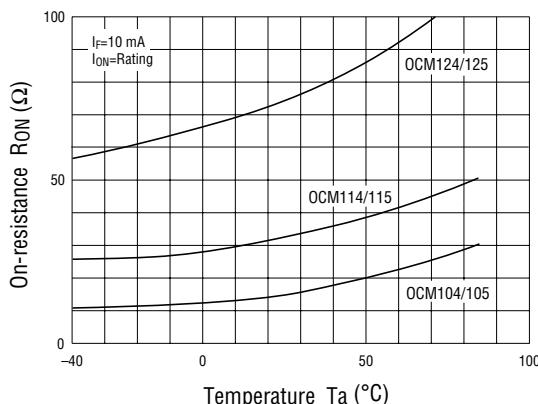
- Operation Input Current vs. Ambient Temperature



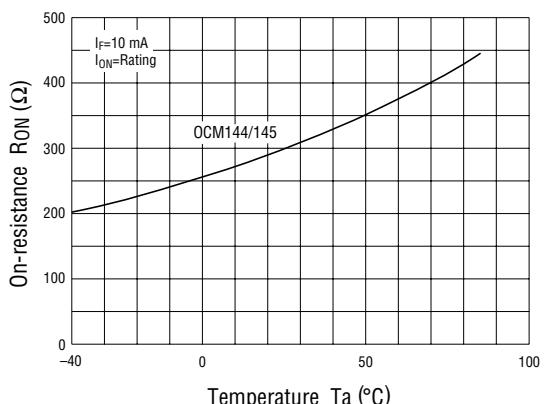
- Recovery Input Current vs. Ambient temperature



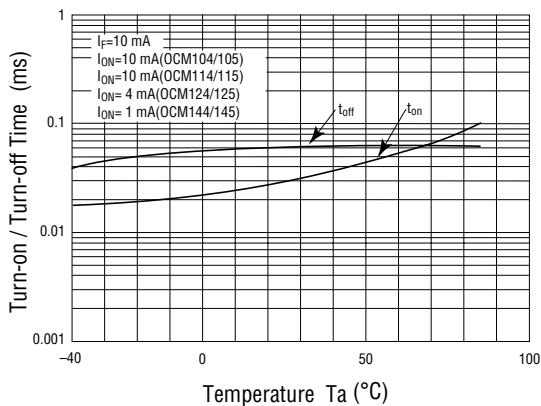
- On-resistance vs. Ambient Temperature 1



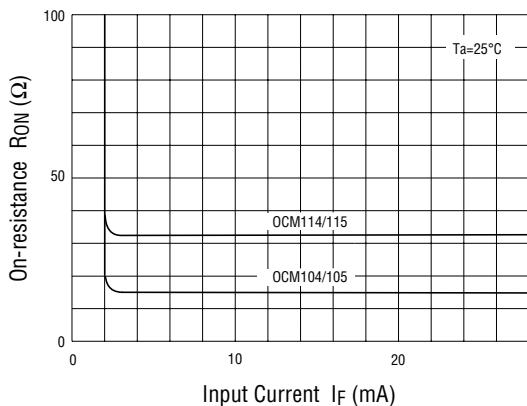
- On-resistance vs. Ambient Temperature 2



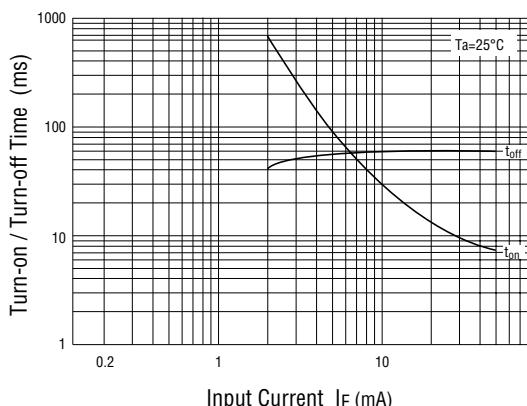
- Turn-on/Turn-off Time vs. Ambient Temperature



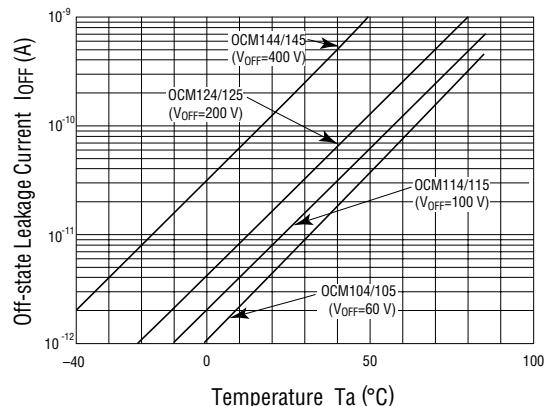
- Continuous Forward Current vs. On-resistance 1



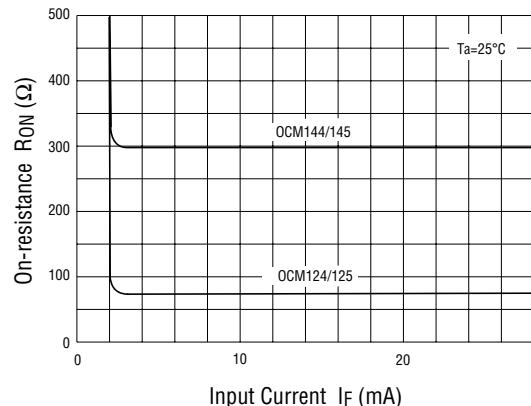
- Continuous Forward Current vs. Turn-on/Turn-off Time



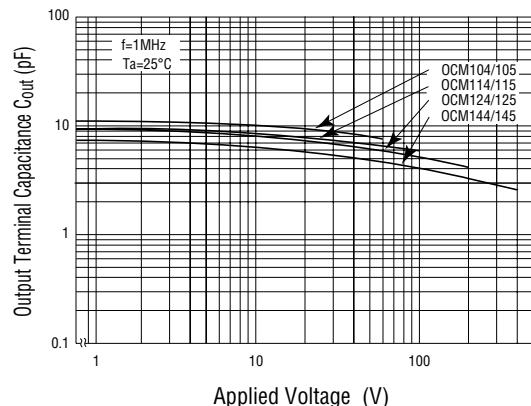
- Off-state Leakage Current vs. Ambient Temperature



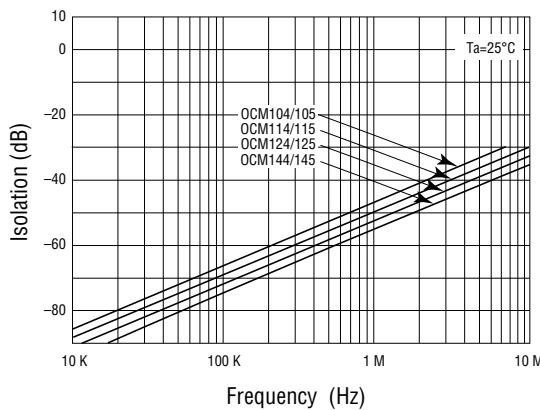
- Continuous Forward Current vs. On-resistance 2



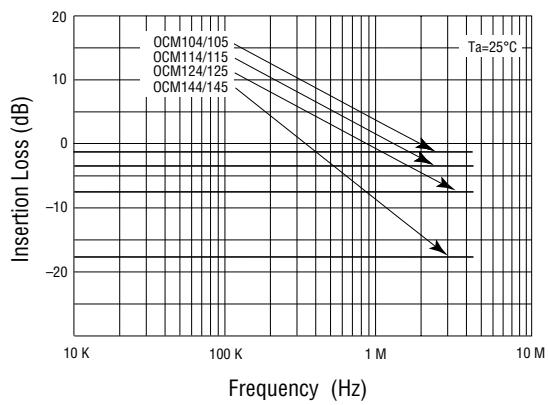
- Output Terminal Capacitance vs. Applied Voltage



- Isolation



- Insertion Loss



- Load Current vs. Voltage

